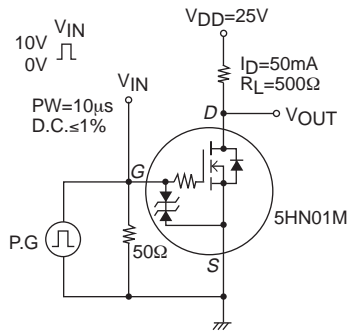


5HN01M

Electrical Characteristics at Ta=25°C

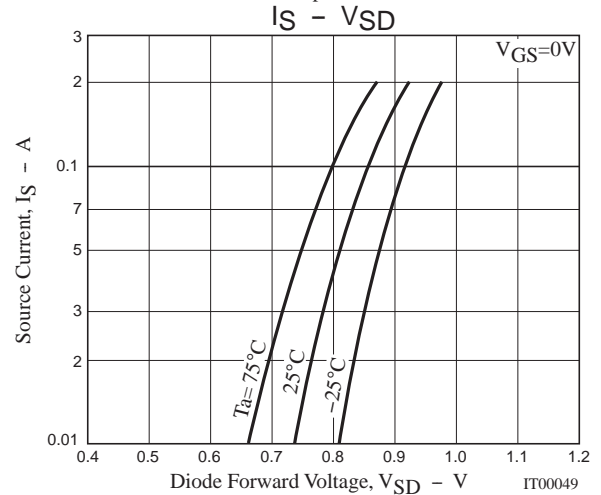
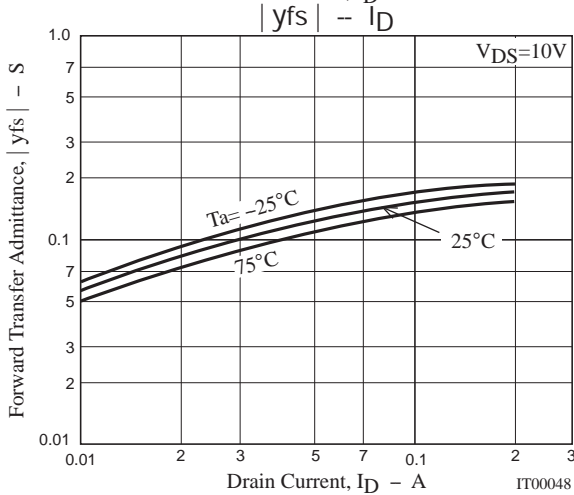
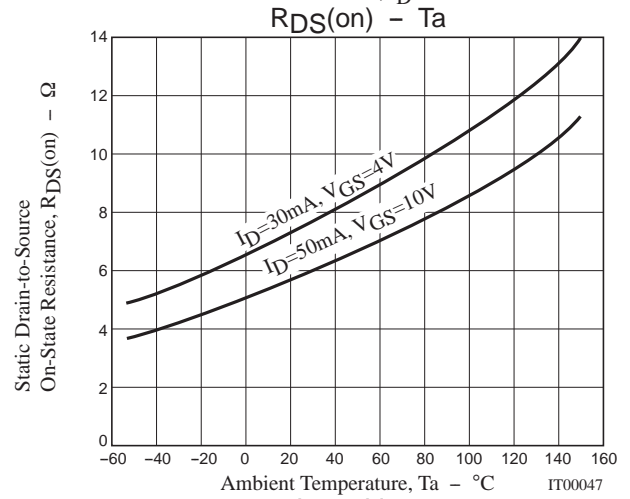
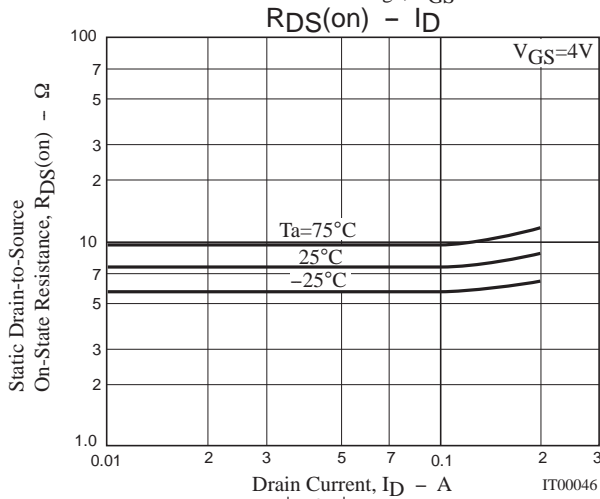
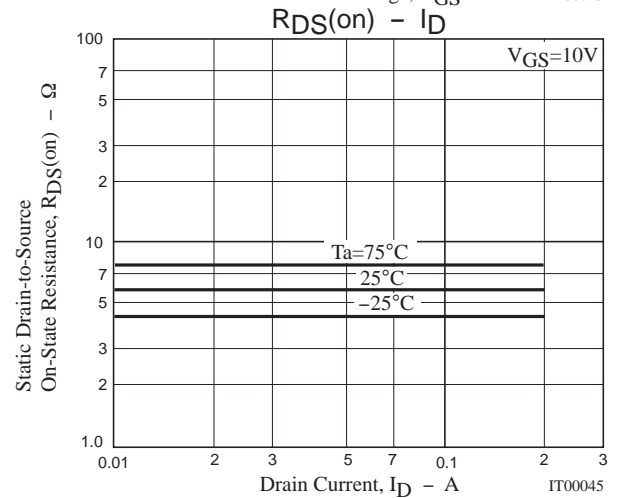
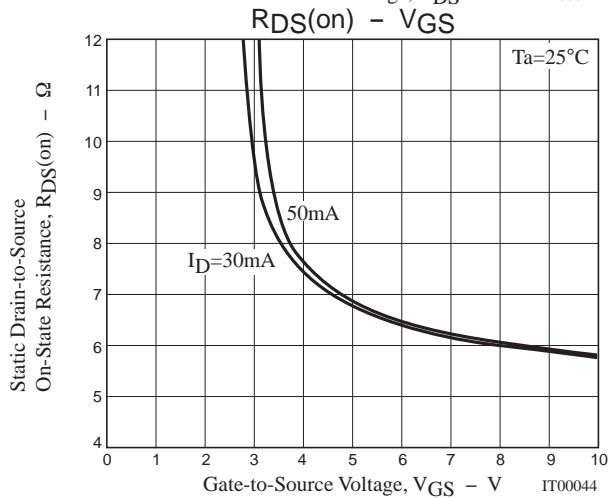
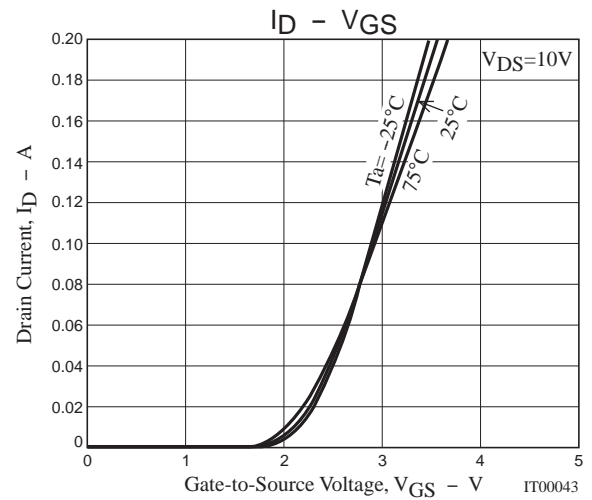
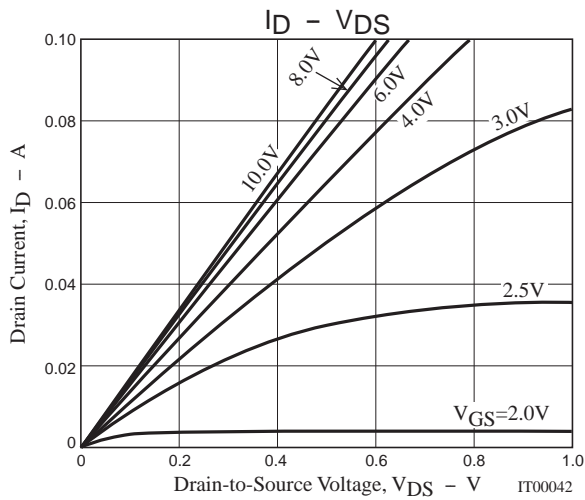
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	50			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =50V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =100μA	1		2.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =50mA	85	120		mS
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =50mA, V _{GS} =10V		5.8	7.5	Ω
	R _{DS(on)2}	I _D =30mA, V _{GS} =4V		7.5	10.5	Ω
Input Capacitance	C _{iss}	V _{DS} =10V, f=1MHz		6.2		pF
Output Capacitance	C _{oss}			4.4		pF
Reverse Transfer Capacitance	C _{rss}			1.5		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		10		ns
Rise Time	t _r			11		ns
Turn-OFF Delay Time	t _{d(off)}			105		ns
Fall Time	t _f			75		ns
Total Gate Charge	Q _g	V _{DS} =10V, V _{GS} =10V, I _D =100mA		1.40		nC
Gate-to-Source Charge	Q _{gs}			0.21		nC
Gate-to-Drain "Miller" Charge	Q _{gd}			0.34		nC
Diode Forward Voltage	V _{SD}	I _S =100mA, V _{GS} =0V		0.85	1.2	V

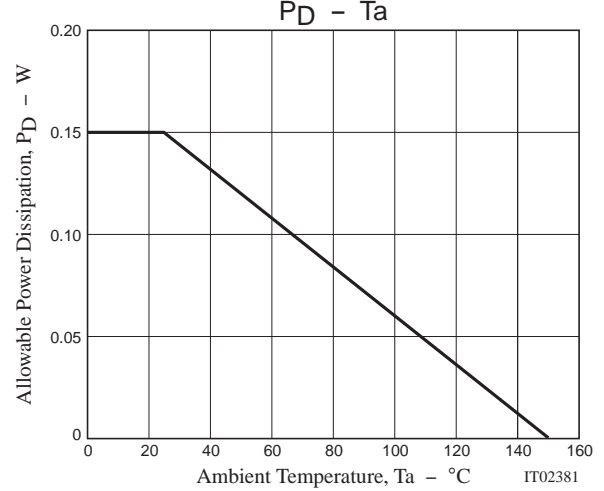
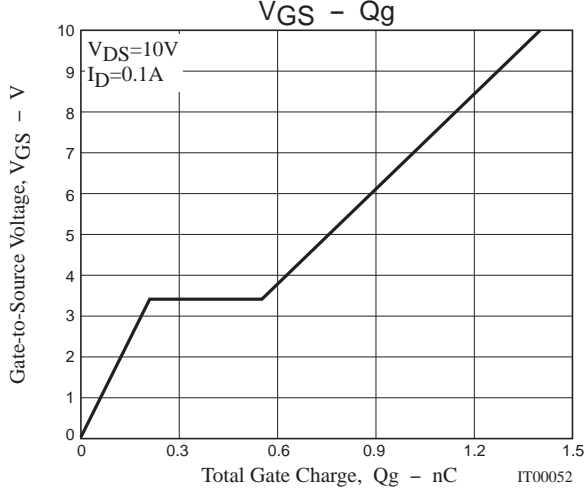
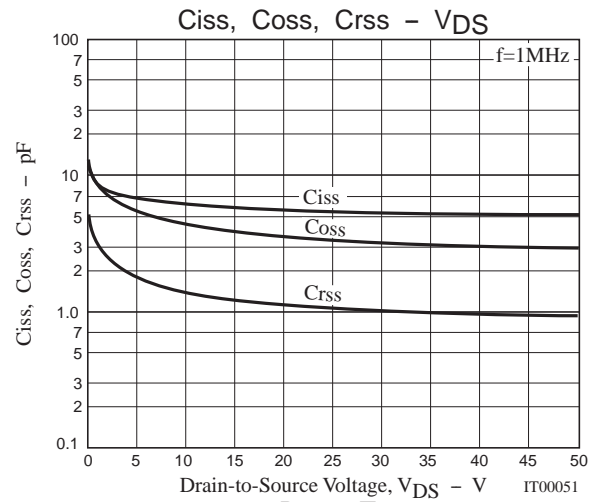
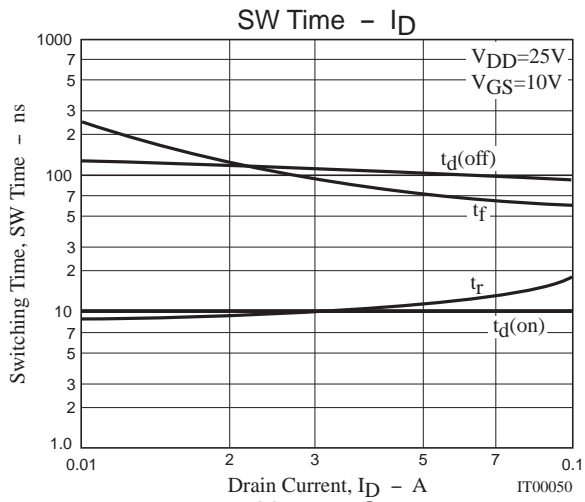
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
5HN01M-TL-E	MCP	3,000pcs./reel	Pb Free
5HN01M-TL-H	MCP	3,000pcs./reel	Pb Free and Halogen Free





Embossed Taping Specification

5HN01M-TL-E, 5HN01M-TL-H

1. Packing Format

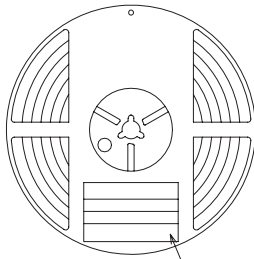
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCP	MCP	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

Outer box label

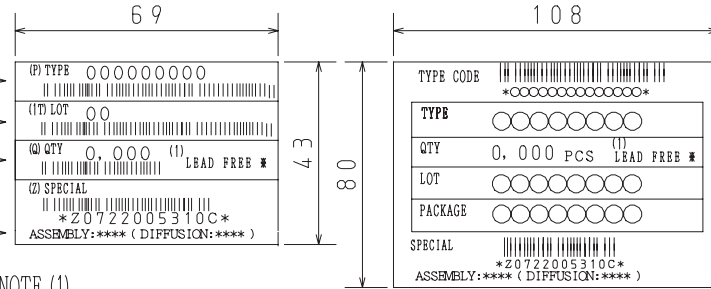
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.
LOT No.
Quantity
Origin



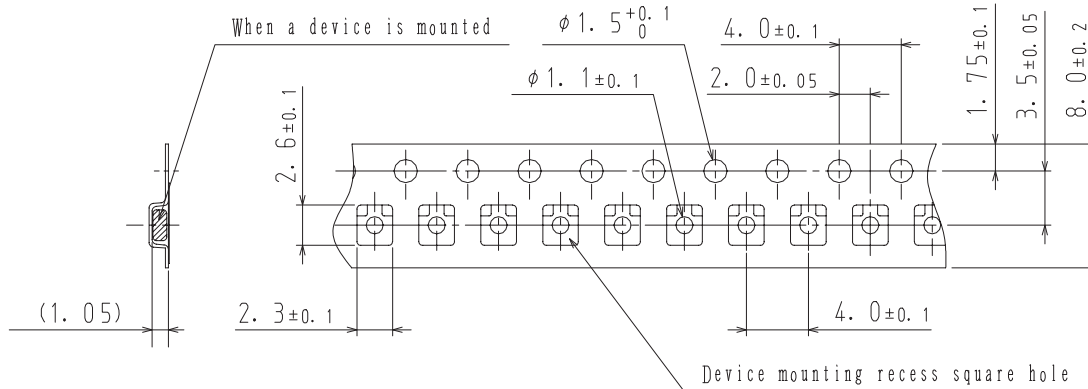
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

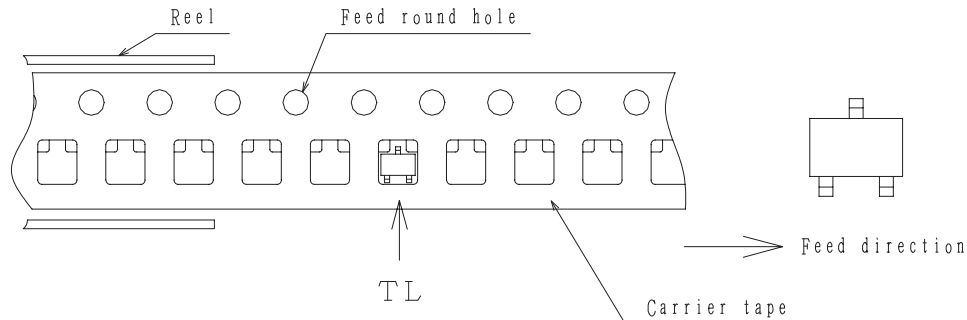
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



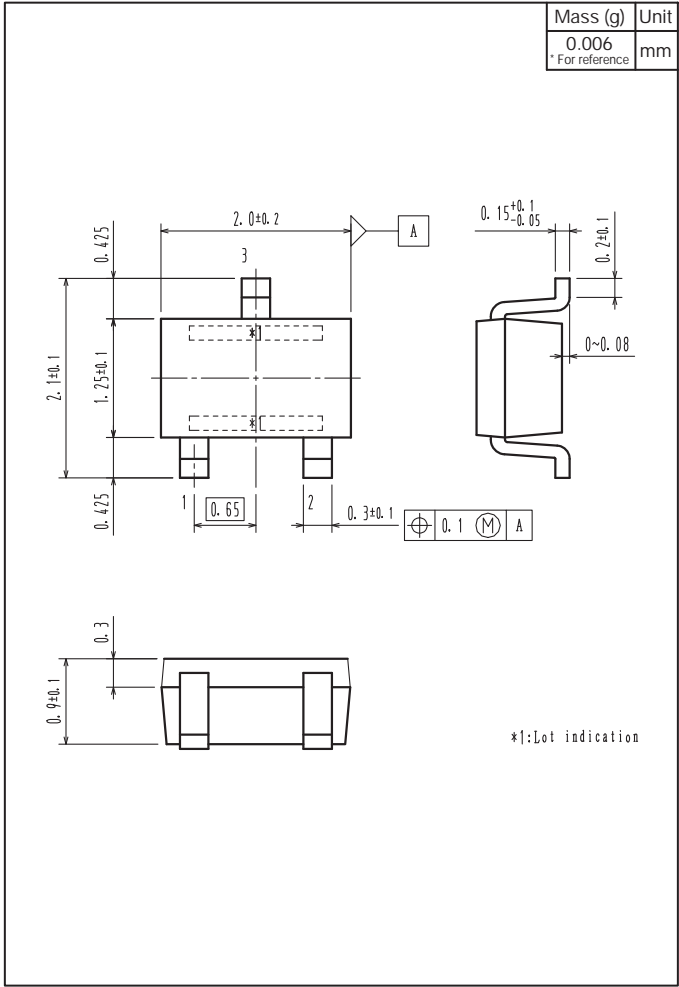
2-2. Device placement direction



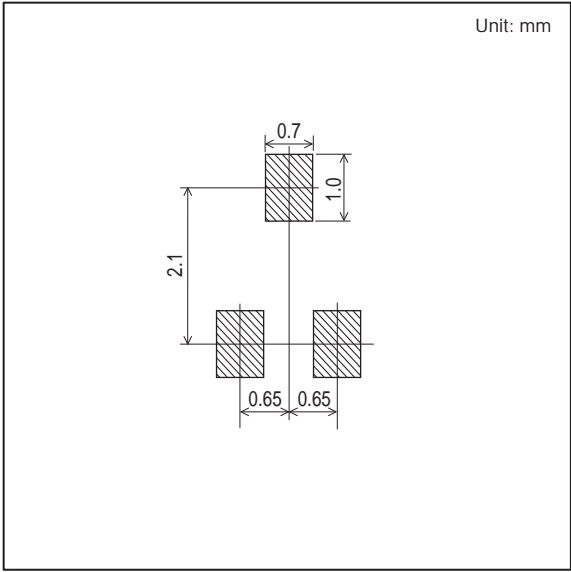
Those with oen electrode terminal on the feed hole side.....TL

Outline Drawing

5HN01M-TL-E, 5HN01M-TL-H



Land Pattern Example



Note on usage : Since the 5HN01M is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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